



N-Channel Enhancement-Mode Vertical DMOS FET

Features

- ▶ Free from secondary breakdown
- ▶ Low power drive requirement
- ▶ Ease of paralleling
- ▶ Low C_{ISS} and fast switching speeds
- ▶ Excellent thermal stability
- ▶ Integral source-drain diode
- ▶ High input impedance and high gain

Applications

- ▶ Motor controls
- ▶ Converters
- ▶ Amplifiers
- ▶ Switches
- ▶ Power supply circuits
- ▶ Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

General Description

This enhancement-mode (normally-off) transistor utilizes a vertical DMOS structure and Supertex's well-proven, silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Ordering Information

| Device | Package Option | BV_{DSS} / BV_{DGS} (V) | $R_{DS(ON)}$ (max) (Ω) | $I_{D(ON)}$ (min) (A) |
|--------|----------------|------------------------------|---------------------------------------|-----------------------------|
| | TO-92 | | | |
| VN1206 | VN1206L-G | 120 | 6.0 | 1.0 |

-G indicates package is RoHS compliant ('Green')



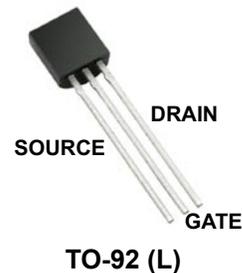
Absolute Maximum Ratings

| Parameter | Value |
|-----------------------------------|-----------------|
| Drain-to-source voltage | BV_{DSS} |
| Drain-to-gate voltage | BV_{DGS} |
| Gate-to-source voltage | $\pm 30V$ |
| Operating and storage temperature | -55°C to +150°C |
| Soldering temperature* | 300°C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

* Distance of 1.6mm from case for 10 seconds.

Pin Configuration



Product Marking



YY = Year Sealed
 WW = Week Sealed
 _____ = "Green" Packaging

Package may or may not include the following marks: Si or

TO-92 (L)

Thermal Characteristics

| Package | I_D (continuous) [†] (mA) | I_D (pulsed) (A) | Power Dissipation @ $T_c = 25^\circ\text{C}$ (W) | θ_{jc} ($^\circ\text{C}/\text{W}$) | θ_{ja} ($^\circ\text{C}/\text{W}$) | I_{DR}^\dagger (mA) | I_{DRM} (A) |
|---------|--|--------------------------|--|--|--|--------------------------|------------------|
| TO-92 | 230 | 2.0 | 1.0 | 125 | 170 | 230 | 2.0 |

Notes:

[†] I_D (continuous) is limited by max rated T_j .

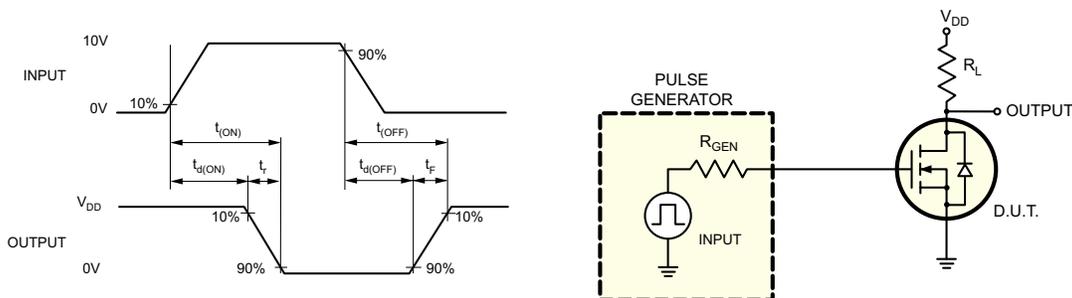
Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified)

| Sym | Parameter | Min | Typ | Max | Units | Conditions |
|--------------|--|-----|-----|-----|---------------|---|
| BV_{DSS} | Drain-to-source breakdown voltage | 120 | - | - | V | $V_{GS} = 0V, I_D = 100\mu\text{A}$ |
| $V_{GS(th)}$ | Gate threshold voltage | 0.8 | - | 2.0 | V | $V_{GS} = V_{DS}, I_D = 1.0\text{mA}$ |
| I_{GSS} | Gate body leakage | - | - | 100 | nA | $V_{GS} = \pm 15V, V_{DS} = 0V$ |
| I_{DSS} | Zero gate voltage drain current | - | - | 10 | μA | $V_{GS} = 0V, V_{DS} = \text{Max Rating}$ |
| | | - | - | 500 | | $V_{DS} = 0.8\text{Max Rating}, V_{GS} = 0V, T_A = 125^\circ\text{C}$ |
| $I_{D(ON)}$ | On-state drain current | 1.0 | - | - | A | $V_{GS} = 10V, V_{DS} = 10V$ |
| $R_{DS(ON)}$ | Static drain-to-source on-state resistance | - | - | 10 | Ω | $V_{GS} = 2.5V, I_D = 100\text{mA}$ |
| | | - | - | 6.0 | | $V_{GS} = 10V, I_D = 500\text{mA}$ |
| G_{FS} | Forward transductance | 300 | - | - | mmho | $V_{DS} = 10V, I_D = 500\text{mA}$ |
| C_{ISS} | Input capacitance | - | - | 125 | pF | $V_{GS} = 0V, V_{DS} = 25V, f = 1.0\text{MHz}$ |
| C_{OSS} | Common source output capacitance | - | - | 50 | | |
| C_{RSS} | Reverse transfer capacitance | - | - | 20 | | |
| t_r | Rise time | - | - | 8.0 | ns | $V_{DD} = 60V, I_D = 400\text{mA}, R_{GEN} = 25\Omega$ |
| $t_{d(ON)}$ | Turn-on delay time | - | - | 8.0 | | |
| t_f | Fall time | - | - | 12 | | |
| $t_{d(OFF)}$ | Turn-off delay time | - | - | 18 | | |
| V_{SD} | Diode forward voltage drop | - | 1.2 | - | V | $V_{GS} = 0V, I_{SD} = 250\text{mA}$ |

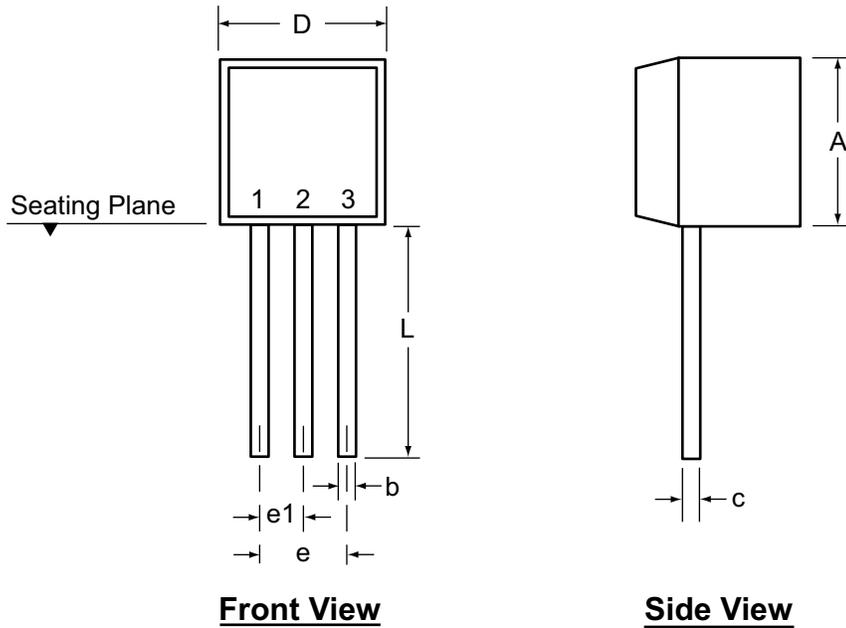
Notes:

1. All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: $300\mu\text{s}$ pulse, 2% duty cycle.)
2. All A.C. parameters sample tested.

Switching Waveforms and Test Circuit



3-Lead TO-92 Package Outline (L)



| Symbol | A | b | c | D | E | E1 | e | e1 | L |
|---------------------|-----|------|-------------------|-------------------|------|------|------|------|-------|
| Dimensions (inches) | MIN | .170 | .014 [†] | .175 | .125 | .080 | .095 | .045 | .500 |
| | NOM | - | - | - | - | - | - | - | - |
| | MAX | .210 | .022 [†] | .022 [†] | .205 | .165 | .105 | .105 | .610* |

JEDEC Registration TO-92.

* This dimension is not specified in the JEDEC drawing.

† This dimension differs from the JEDEC drawing.

Drawings not to scale.

Supertex Doc.#: DSPD-3TO92N3, Version E041009.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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